imall

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DMG264H0

Silicon NPN epitaxial planar type (Tr1) Silicon PNP epitaxial planar type (Tr2)

For digital circuits

Features

- \bullet Low collector-emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)
- Marking Symbol: T0

Basic Part Number

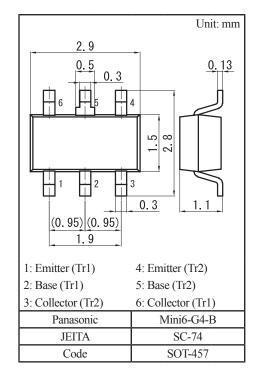
DRC2144E + DRA2543E (Individual)

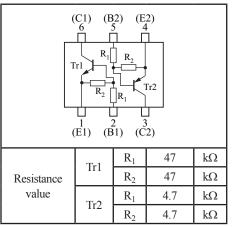
Packaging

DMG264H00R Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

| Parameter | | Symbol | Rating | Unit | |
|-----------|---------------------------------------|------------------|-------------|------|--|
| Tr1 | Collector-base voltage (Emitter open) | V _{CBO} | 50 | V | |
| | Collector-emitter voltage (Base open) | V _{CEO} | 50 | V | |
| | Collector current | I _C | 100 | mA | |
| Tr2 | Collector-base voltage (Emitter open) | V _{CBO} | -50 | V | |
| | Collector-emitter voltage (Base open) | V _{CEO} | -50 | V | |
| | Collector current | I _C | -500 | mA | |
| | Total power dissipation | P _T | 300 | mW | |
| Overall | Junction temperature | Tj | 150 | °C | |
| | Operating ambient temperature | T _{opr} | -40 to +85 | °C | |
| | Storage temperature | T _{stg} | -55 to +150 | °C | |





Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

• Tr1

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|---------------------------------|---|------|-----|------|------|
| Collector-base voltage (Emitter open) | V _{CBO} | $I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$ | 50 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_{\rm C} = 2 {\rm mA}, I_{\rm B} = 0$ | 50 | | | V |
| Collector-base cutoff current (Emitter open) | I _{CBO} | $V_{CB} = 50 \text{ V}, I_E = 0$ | | | 0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 50 \text{ V}, I_{B} = 0$ | | | 0.5 | μΑ |
| Emitter-base cutoff current (Collector open) | I _{EBO} | $V_{EB} = 6 V, I_C = 0$ | | | 0.1 | mA |
| Forward current transfer ratio | h _{FE} | $V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$ | 80 | | | |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}$ | | | 0.25 | V |
| Input voltage (ON) | V _{I(on)} | $V_{\rm CE} = 0.2$ V, $I_{\rm C} = 5$ mA | 3.6 | | | V |
| Input voltage (OFF) | V _{I(off)} | $V_{CE} = 5 \text{ V}, I_C = 100 \mu\text{A}$ | | | 0.8 | V |
| Input resistance | R ₁ | | -30% | 47 | +30% | kΩ |
| Resistance ratio | R ₁ / R ₂ | | 0.8 | 1.0 | 1.2 | |

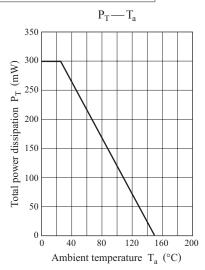
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

| • Tr2 |
|-------|
|-------|

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|--|------|-----|-------|------|
| Collector-base voltage (Emitter open) | V _{CBO} | $I_{\rm C} = -10 \ \mu {\rm A}, I_{\rm E} = 0$ | -50 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_{\rm C} = -2 {\rm mA}, I_{\rm B} = 0$ | -50 | | | V |
| Collector-base cutoff current (Emitter open) | I _{CBO} | $V_{CB} = -50 \text{ V}, I_E = 0$ | | | -1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{\rm CE} = -50$ V, $I_{\rm B} = 0$ | | | -1 | μΑ |
| Emitter-base cutoff current (Collector open) | I _{EBO} | $V_{\rm EB} = -6 \text{V}, \text{I}_{\rm C} = 0$ | | | -2 | mA |
| Forward current transfer ratio | $h_{\rm FE}$ | $V_{CE} = -10 \text{ V}, I_C = -100 \text{ mA}$ | 50 | | | |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = -100 \text{ mA}, I_{\rm B} = -5 \text{ mA}$ | | | -0.25 | V |
| Input voltage (ON) | V _{I(on)} | $V_{\rm CE} = -0.2$ V, $I_{\rm C} = -50$ mA | -3.6 | | | V |
| Input voltage (OFF) | V _{I(off)} | $V_{CE} = -5 V, I_C = -100 \mu A$ | | | -0.7 | V |
| Input resistance | R ₁ | | -30% | 4.7 | +30% | kΩ |
| Resistance ratio | R_1 / R_2 | | 0.8 | 1.0 | 1.2 | |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart



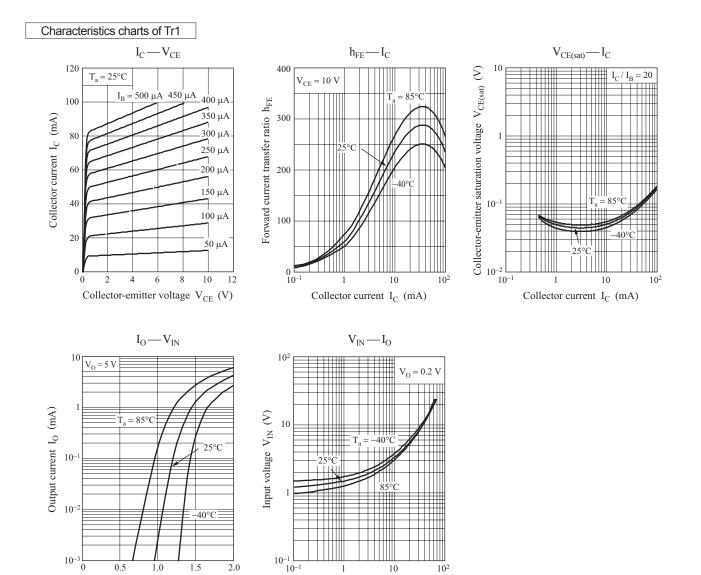
0.5

1.0

Input voltage V_{IN} (V)

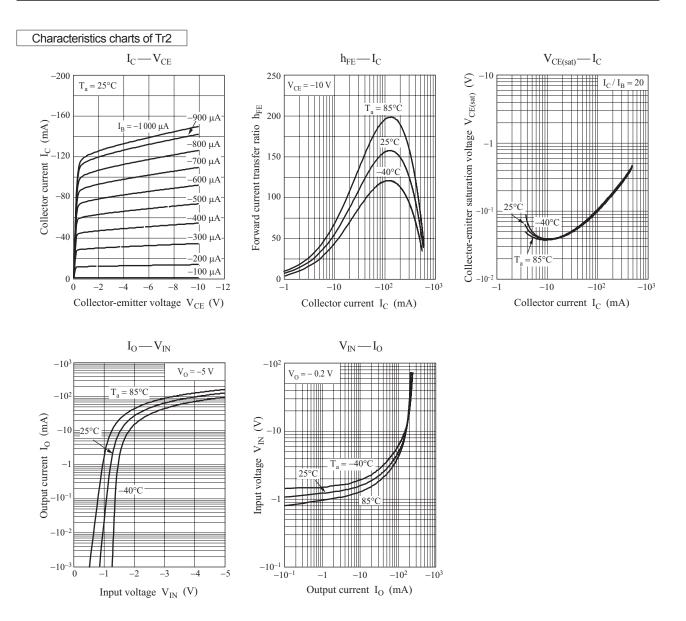
1.5

2.0

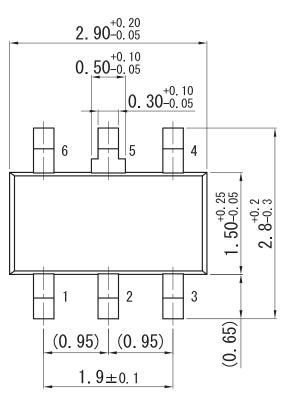


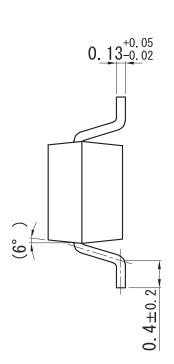


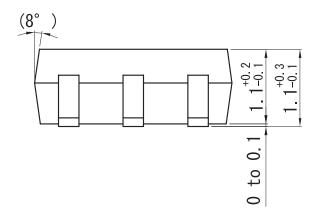
102



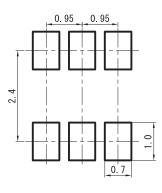
Mini6-G4-B







Land Pattern (Reference) (Unit: mm)



Unit: mm

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